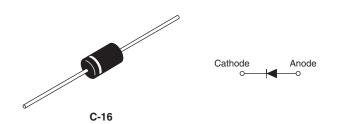
**Vishay Semiconductors** 

# Schottky Rectifier, 3.3 A



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PRODUCT SUMMARY				
Package	DO-201AD (C-16)			
I <sub>F(AV)</sub>	3.3 A			
V <sub>R</sub>	90 V, 100 V			
V <sub>F</sub> at I <sub>F</sub>	See Electrical table			
I <sub>RM</sub> max.	3.0 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
E <sub>AS</sub>	3.0 mJ			

#### **FEATURES**

- · Low profile, axial leaded outline
- High frequency operation
- Very low forward voltage drop
- High purity, high temperature epoxy encapsulation forenhanced mechanical strength and moisture resistance



HALOGEN

**FREE** Available

- Guard ring for enhanced ruggedness and long termreliability
- Compliant to RoHS Directive 2002/95/EC
- · Designed and qualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

### DESCRIPTION

The VS-31DQ..G... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	3.3	A		
V <sub>RRM</sub>		90/100	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	370	А		
V <sub>F</sub>	3 Apk, T <sub>J</sub> = 25 °C	0.85	V		
TJ		- 40 to 150	°C		

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-31DQ09G	VS-31DQ09G-M3	VS-31DQ10G	VS-31DQ10G-M3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>							
Maximum working peak reverse voltage	V <sub>RWM</sub>	90	90	100	100	V		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS V		VALUES	UNITS
Maximum average forward current See fig. 4	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 53.4 °C, rectangular waveform 3.3			
Maximum peak one cycle non-repetitive surge current, T,I = 25 °C	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	370	А
See fig. 6		10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	60	
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, 18 \ \mu \text{s}$ square pulse 3.0 r		mJ	
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 0.5		А	

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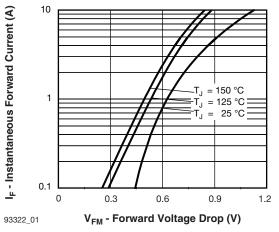
ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS VAL		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	3 A	T <sub>J</sub> = 25 °C	0.85	V
		6 A		0.97	
		3 A	T <sub>J</sub> = 125 °C	0.69	
		6 A		0.80	
Maximum reverse leakage current	I <sub>BM</sub> <sup>(1)</sup>	$T_J = 25 \ ^{\circ}C$	V <sub>R</sub> = Rated V <sub>R</sub>	0.1	mA
See fig. 2	IRM \''	T <sub>J</sub> = 125 °C		3	
Typical junction capacitance	C <sub>T</sub>	$V_{\text{R}}$ = 5 $V_{\text{DC}}$ (test signal range 100 kHz to 1 MHz) 25 $^{\circ}\text{C}$		110	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body 9.0 nl		nH	
Maximum voltage rate of charge	dV/dt	Rated V <sub>R</sub> 10 000 V/μs		V/µs	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation Without cooling fin	80	°C/W
Typical thermal resistance, junction to lead	R <sub>thJL</sub>	DC operation	34	C/W
Approximate weight			1.2	g
			0.042	oz.
Marking davias		Case style C-16	31DQ09G	
Marking device		Case signe C-10	31DQ10G	

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Fig. 1 - Maximum Forward Voltage Drop Characteristics

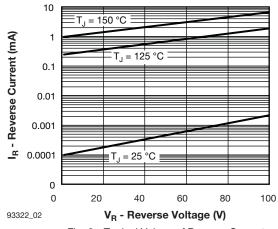
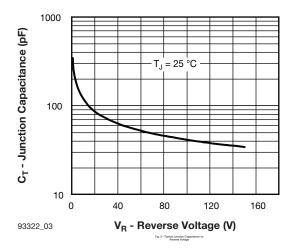
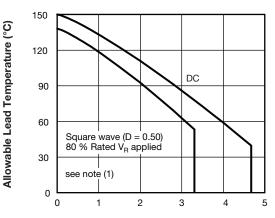


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage





93322\_04 **I<sub>F(AV)</sub> - Average Forward Current (A)** Fig. 4 - Maximum Allowable Lead Temperature vs. Average Forward Current

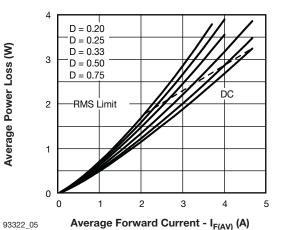
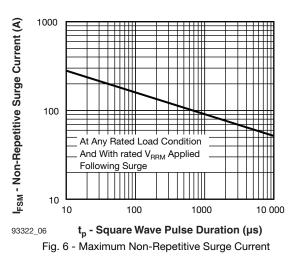


Fig. 5 - Forward Power Loss Characteristics



Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6);  $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$ 

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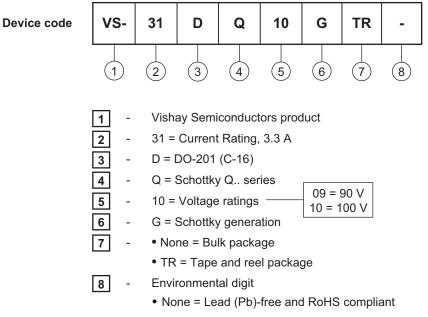
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### **ORDERING INFORMATION TABLE**



• -M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-31DQ09G	500	500	Bulk	
VS-31DQ09GTR	1200	1200	Tape and reel	
VS-31DQ09G-M3	500	500	Bulk	
VS-31DQ09GTR-M3	1200	1200	Tape and reel	
VS-31DQ10G	500	500	Bulk	
VS-31DQ10GTR	1200	1200	Tape and reel	
VS-31DQ10G-M3	500	500	Bulk	
VS-31DQ10GTR-M3	1200	1200	Tape and reel	

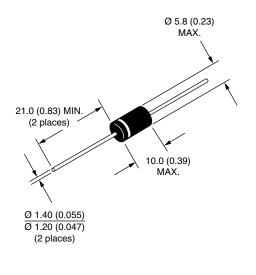
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95242			
Part marking information	www.vishay.com/doc?95304			
Packaging information	www.vishay.com/doc?95338			
SPICE model	www.vishay.com/doc?95300			

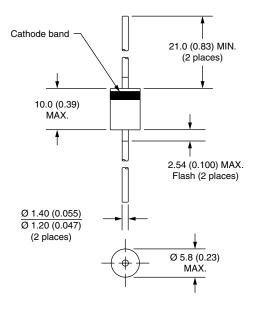




Axial DO-201AD (C-16)

#### **DIMENSIONS** in millimeters (inches)







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